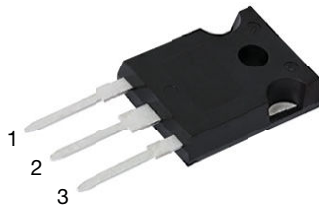
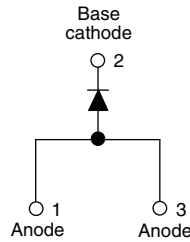


Hyperfast Rectifier, 60 A FRED Pt[®]



TO-247AC 3L



FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- Low leakage current
- Soft recovery device
- 175 °C operating junction temperature
- Designed and qualified according to JEDEC[®]-JESD 47
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912



RoHS
COMPLIANT
HALOGEN
FREE

DESCRIPTION / APPLICATIONS

VS-60APH03-N3 series are the state of the art ultrafast recovery rectifiers designed with optimized performance of forward voltage drop and ultrafast recovery time.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for PDP and use in the output rectification stage for SMPS, UPS, DC/DC converters as well as freewheeling diodes in low voltage inverters.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

PRIMARY CHARACTERISTICS

$I_{F(AV)}$	60 A
V_R	300 V
V_F at I_F	0.85 V
t_{rr} typ.	28 ns
T_J max.	175 °C
Package	TO-247AC 3L
Circuit configuration	Single

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Cathode to anode voltage	V_R		300	V
Continuous forward current	$I_{F(AV)}$	$T_C = 103\text{ °C}$	60	A
Single pulse forward current	I_{FSM}	$T_J = 25\text{ °C}, t_p = 10\text{ ms}$	450	
Operating junction and storage temperatures	T_J, T_{Stg}		-55 to +175	°C

ELECTRICAL SPECIFICATIONS ($T_J = 25\text{ °C}$ unless otherwise specified)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Breakdown voltage, blocking voltage	V_{BR}, V_R	$I_R = 100\text{ }\mu\text{A}$	300	-	-	V
Forward voltage	V_F	$I_F = 30\text{ A}$	-	1.0	1.25	
		$I_F = 60\text{ A}$	-	-	1.45	
		$I_F = 30\text{ A}, T_J = 125\text{ °C}$	-	0.85	1.10	
		$I_F = 60\text{ A}, T_J = 125\text{ °C}$	-	-	1.30	
Reverse leakage current	I_R	$V_R = V_R$ rated	-	-	10	μA
		$T_J = 125\text{ °C}, V_R = V_R$ rated	-	-	100	
Junction capacitance	C_T	$V_R = 300\text{ V}$	-	70	-	pF
Series inductance	L_S	Measured lead to lead 5 mm from package body	-	3.5	-	nH

DYNAMIC RECOVERY CHARACTERISTICS ($T_J = 25\text{ }^\circ\text{C}$ unless otherwise specified)						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Reverse recovery time	t_{rr}	$I_F = 1.0\text{ A}$, $di_F/dt = 100\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	28	-	ns
		$I_F = 1.0\text{ A}$, $di_F/dt = 50\text{ A}/\mu\text{s}$, $V_R = 30\text{ V}$	-	34	-	
		$T_J = 25\text{ }^\circ\text{C}$	-	42	-	
		$T_J = 125\text{ }^\circ\text{C}$	-	64	-	
Peak recovery current	I_{RRM}	$T_J = 25\text{ }^\circ\text{C}$	-	3.0	-	A
		$T_J = 125\text{ }^\circ\text{C}$	-	8.5	-	
Reverse recovery charge	Q_{rr}	$T_J = 25\text{ }^\circ\text{C}$	-	65	-	nC
		$T_J = 125\text{ }^\circ\text{C}$	-	273	-	

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage temperature range	T_J , T_{Stg}		-55	-	175	$^\circ\text{C}$
Thermal resistance, junction to case	R_{thJC}		-	0.56	0.80	$^\circ\text{C}/\text{W}$
Thermal resistance, junction to ambient	R_{thJA}	Typical socket mount	-	-	40	
Typical thermal resistance, case to heatsink	R_{thCS}	Mounting surface, flat, smooth, and greased	-	0.4	-	
Approximate Weight			-	6.0	-	g
			-	0.22	-	oz.
Mounting torque			6.0	-	12	kgf. cm
			(12)	-	(10)	(lbf.in)
Marking device		Case style TO-247AC	60APH03			

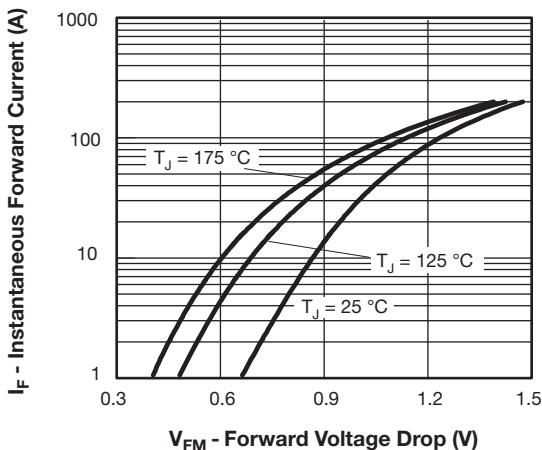


Fig. 1 - Typical Forward Voltage Drop Characteristics

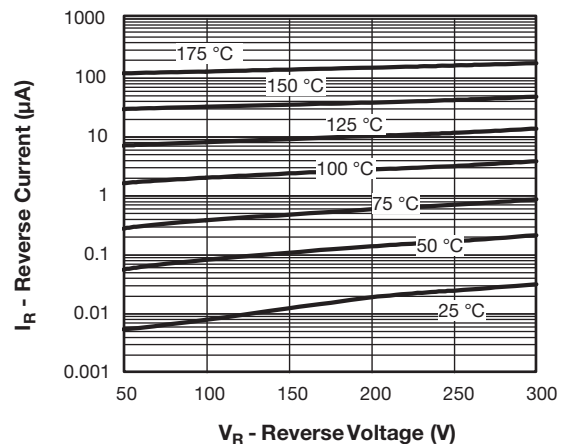


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

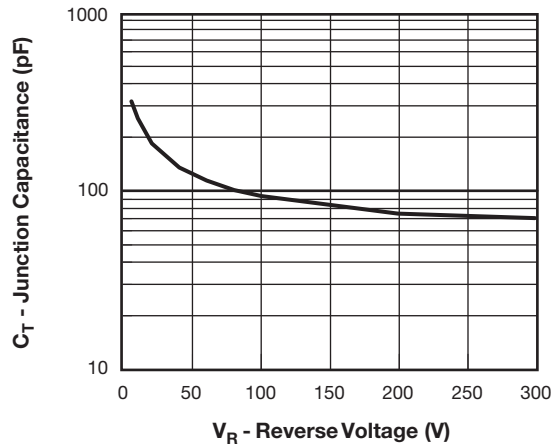


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

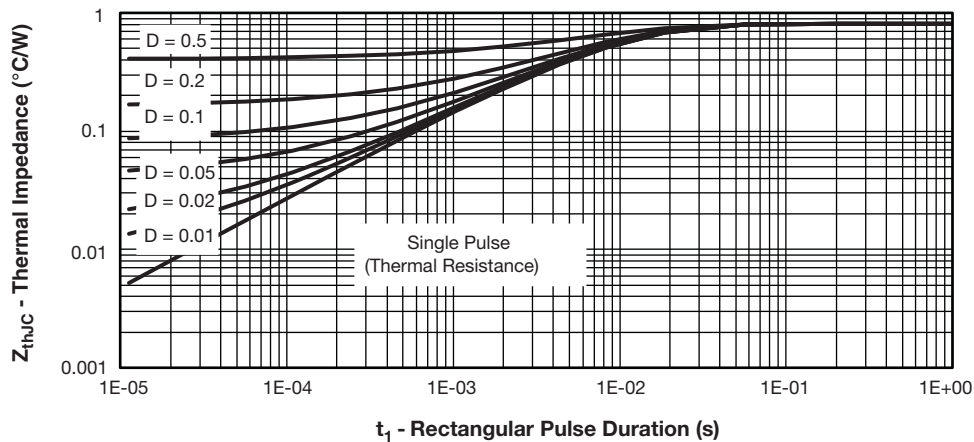


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

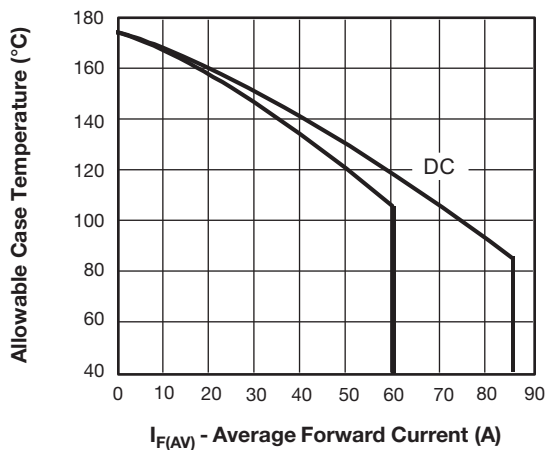


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

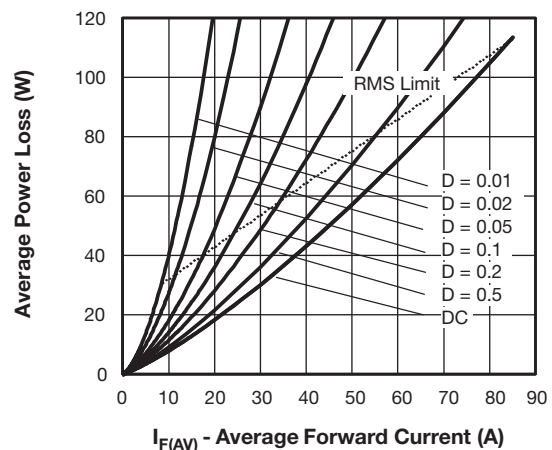


Fig. 6 - Forward Power Loss Characteristics

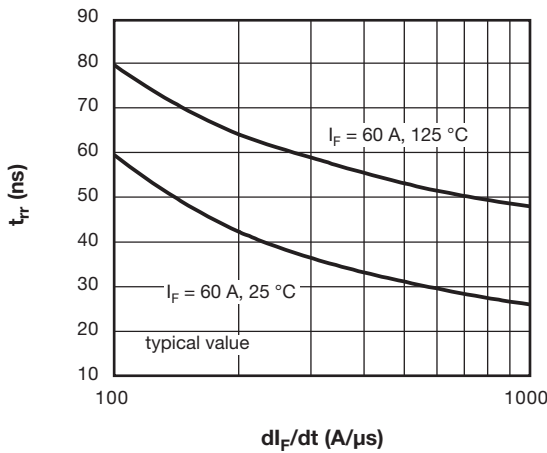


Fig. 7 - Typical Reverse Recovery vs. di_F/dt

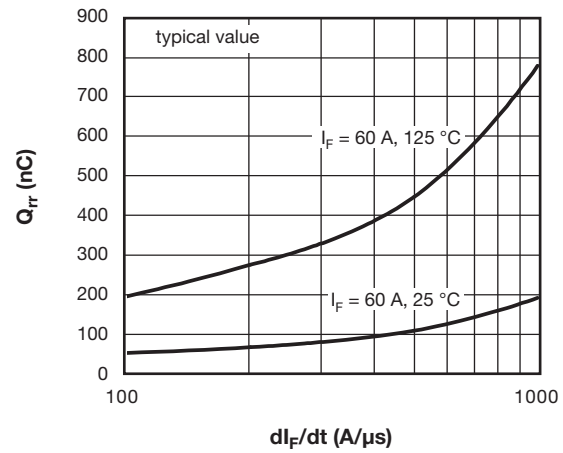
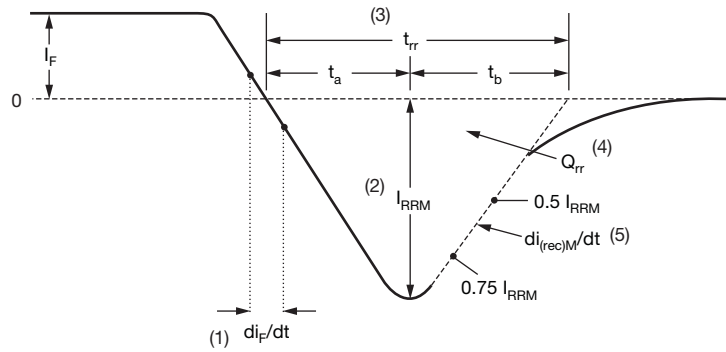


Fig. 8 - Typical Stored Charge vs. di_F/dt



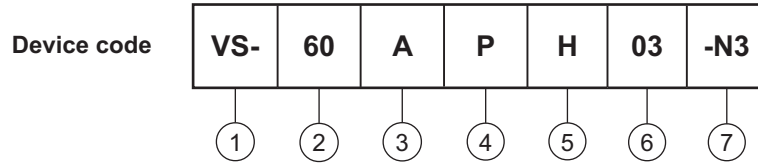
- (1) di_F/dt - rate of change of current through zero crossing
- (2) I_{RRM} - peak reverse recovery current
- (3) t_{rr} - reverse recovery time measured from zero crossing point of negative going I_F to point where a line passing through $0.75 I_{RRM}$ and $0.50 I_{RRM}$ extrapolated to zero current.
- (4) Q_{rr} - area under curve defined by t_{rr} and I_{RRM}
- (5) $di_{(rec)M}/dt$ - peak rate of change of current during t_b portion of t_{rr}

$$Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$$

Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE



- 1** - Vishay Semiconductors product
- 2** - Current rating (60 = 60 A)
- 3** - Circuit configuration:
A = single diode, 3 pins
- 4** - P = TO-247 AC
- 5** - H = hyperfast rectifier
- 6** - Voltage code (03 = 300 V)
- 7** - -N3 = halogen-free, RoHS-compliant, and totally lead (Pb)-free

ORDERING INFORMATION (Example)			
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION
VS-60APH03-N3	25	500	Antistatic plastic tube

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?96138
Part marking information	www.vishay.com/doc?95007
SPICE model	www.vishay.com/doc?96075